

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2771	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and active with layer and (host support\$3) and (oxygen nitrogen)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/22 16:20
S2	390	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and active with layer and (host support\$3) and (oxygen nitrogen) and cleav\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/22 16:21
S6	615	"5374564"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/22 17:21
S7	14	"6245645"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/22 17:21
S8	2	"5374564".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/22 17:23
S9	219374	"438"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 10:49
S10	4382	S9 and implant\$5 with active with layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 10:50
S11	686	S10 and (insulat\$3 dielectric) and bond\$3 and (heat\$3 anneal\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 10:51

S12	75	S11 and cleav\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 10:51
S13	1	"11851065"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 13:29
S14	30	"6613678"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 13:55
S15	2	"20010029072"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 14:04
S16	211	"5882987"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 14:04
S18	2797	438/455	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 14:58
S19	2775	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and active with layer and (host support\$3) and (oxygen nitrogen)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 14:59
S20	202	S18 and S19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 14:59
S21	3	"20050255671"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 15:25

S22	2258	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and active with layer and (host support\$3) and (oxygen nitrogen) and plasma	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 16:34
S23	876	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and active with layer and (host support\$3) and (oxygen nitrogen) and plasma with (treat\$5 clean\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/28 16:40
S24	33	"6255195"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 10:30
S25	2111	438/458	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 10:48
S26	2781	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and active with layer and (host support\$3) and (oxygen nitrogen)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 10:48
S27	167	S25 and S26	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 10:48
S28	1897	ion with implant\$5 and bond\$3 and (heat\$3 anneal\$3) and (host support\$3) and (oxygen nitrogen) and plasma with (clean\$3 treat\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 11:48
S29	2804	438/455	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 11:48

S30	135	S29 and S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/31 11:48
S31	2968	(ion with implant\$5 ion \$1implant\$5) and bond \$3 and (heat\$3 anneal \$3) and active with layer and (host support \$3) and (oxygen nitrogen)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 14:45
S32	156678	(ion with implant\$5 ion \$1implant\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 14:45
S33	1590	(ion with implant\$5 ion \$1implant\$5) and (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 14:48
S34	494	(ion with implant\$5 ion \$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 14:49
S35	222	(ion with implant\$5 ion \$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) with bubbl\$2 and (cleav\$3 separat\$3) and bubbl\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 14:49

S36	18	((ion with implant\$5 ion\$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3) and ((ion with implant\$5 ion\$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 14:50
S37	108	((ion with implant\$5 ion\$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3) and plasma with treat\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/12 15:36
S38	494	((ion with implant\$5 ion\$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/15 14:11
S39	18	((ion with implant\$5 ion\$1implant\$5) with (hydrogen helium light with element) and (insulat\$3 dielectric oxide) and bond\$3 and (heat\$3 anneal\$3) and (cleav\$3 separat\$3) and bubbl\$3).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/15 16:58

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